## C4D10120E-Silicon Carbide Schottky Diode Z-REC ${ }^{\text {Tm }}$ Rectifier

$$
\begin{aligned}
& \mathbf{V}_{\mathbf{R R M}}=1200 \mathrm{~V} \\
& \mathbf{I}_{\mathrm{F}(\mathrm{AVG})}=10 \mathrm{~A} \\
& \mathbf{Q}_{\mathbf{c}}=66 \mathrm{nC}
\end{aligned}
$$

## Features

- 1200-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Positive Temperature Coefficient on $\mathrm{V}_{\mathrm{F}}$


## Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway


## Applications

- Solar Inverters
- Power Factor Correction


## Package



TO-252-2


| Part Number | Package | Marking |
| :---: | :---: | :---: |
| C4D10120E | TO-252-2 | C4D10120 |

Maximum Ratings

| Symbol | Parameter | Value | Unit | Test Conditions | Note |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\text {RRM }}$ | Repetitive Peak Reverse Voltage | 1200 | V |  |  |
| $V_{\text {RSM }}$ | Surge Peak Reverse Voltage | 1300 | V |  |  |
| $V_{\text {DC }}$ | DC Blocking Voltage | 1200 | V |  |  |
| $\mathrm{I}_{\text {(AVG) }}$ | Average Forward Current | 16.1 | A | $\mathrm{T}_{\mathrm{C}}=135^{\circ} \mathrm{C}$; No AC component |  |
| $\mathrm{I}_{\text {FRM }}$ | Repetitive Peak Forward Surge Current | $\begin{gathered} 47 \\ 31.5 \end{gathered}$ | A | $T_{C}=25^{\circ} \mathrm{C}, \mathrm{t}_{\mathrm{p}}=10 \mathrm{~ms}$, Half Sine pulse $\mathrm{T}_{\mathrm{C}}=110^{\circ} \mathrm{C}, \mathrm{t}_{\mathrm{p}}=10 \mathrm{~ms}$, Half Sine pulse |  |
| $\mathrm{I}_{\text {FSM }}$ | Non-Repetitive Peak Forward Surge Current | $\begin{gathered} 71 \\ 59.5 \end{gathered}$ | A | $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}, \mathrm{t}_{\mathrm{p}}=10 \mathrm{~ms}$, Half Sine pulse $\mathrm{T}_{\mathrm{C}}=110^{\circ} \mathrm{C}, \mathrm{t}_{\mathrm{p}}=10 \mathrm{~ms}$, Half Sine pulse |  |
| $\mathrm{P}_{\text {tot }}$ | Power Dissipation | $\begin{gathered} 170.5 \\ 73.9 \end{gathered}$ | W | $\begin{aligned} & \mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C} \\ & \mathrm{~T}_{\mathrm{C}}=110^{\circ} \mathrm{C} \end{aligned}$ |  |
| T ${ }_{\text {c }}$ | Maximum Case Temperature | 135 | ${ }^{\circ} \mathrm{C}$ |  |  |
| T ${ }_{\text {J }}$ | Operating Junction Range | $\begin{aligned} & -55 \text { to } \\ & +175 \end{aligned}$ | ${ }^{\circ} \mathrm{C}$ |  |  |
| $\mathrm{T}_{\text {stg }}$ | Storage Temperature Range | $\begin{aligned} & -55 \text { to } \\ & +135 \end{aligned}$ | ${ }^{\circ} \mathrm{C}$ |  |  |

## Electrical Characteristics

| Symbol | Parameter | Typ. | Max. | Unit | Test Conditions | Note |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $V_{F}$ | Forward Voltage | $\begin{aligned} & 1.5 \\ & 2.2 \end{aligned}$ | $\begin{gathered} 1.8 \\ 3 \end{gathered}$ | V | $\begin{aligned} & \mathrm{I}_{\mathrm{F}}=10 \mathrm{~A} \quad \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \\ & \mathrm{I}_{\mathrm{F}}=10 \mathrm{~A} \quad \mathrm{~T}_{\mathrm{J}}=175^{\circ} \mathrm{C} \\ & \hline \end{aligned}$ |  |
| $\mathrm{I}_{\mathrm{R}}$ | Reverse Current | $\begin{aligned} & \hline 30 \\ & 55 \end{aligned}$ | $\begin{aligned} & 250 \\ & 350 \end{aligned}$ | $\mu \mathrm{A}$ | $\begin{aligned} & \hline V_{R}=1200 \vee \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \\ & \mathrm{~V}_{\mathrm{R}}=1200 \vee \mathrm{~T}_{\mathrm{J}}=175^{\circ} \mathrm{C} \\ & \hline \end{aligned}$ |  |
| $\mathrm{Q}_{\mathrm{C}}$ | Total Capacitive Charge | 66 |  | nC | $\begin{aligned} & \mathrm{V}_{\mathrm{R}}=1200 \mathrm{~V}, \mathrm{I}_{\mathrm{F}}=10 \mathrm{~A} \\ & \mathrm{~d} i / \mathrm{d} t=200 \mathrm{~A} / \mu \mathrm{S} \\ & \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C} \end{aligned}$ |  |
| C | Total Capacitance | $\begin{gathered} 754 \\ 45 \\ 38 \\ \hline \end{gathered}$ |  | pF | $\begin{aligned} & \mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}, \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C}, \mathrm{f}=1 \mathrm{MHz} \\ & \mathrm{~V}_{\mathrm{R}}=400{\mathrm{~V}, \mathrm{~T}_{\mathrm{J}}=25^{\circ}{ }^{\circ} \mathrm{C}, \mathrm{f}=1 \mathrm{MHz}}_{\mathrm{V}_{\mathrm{R}}=800 \mathrm{~V}, \mathrm{~T}_{\mathrm{J}}=25^{\circ} \mathrm{C}, \mathrm{f}=1 \mathrm{MHz}} \end{aligned}$ |  |

## Note:

1. This is a majority carrier diode, so there is no reverse recovery charge.

## Thermal Characteristics

| Symbol | Parameter | Typ. | Unit |
| :---: | :--- | :---: | :---: |
| $\mathrm{R}_{\text {өл }}$ | TO-252 Package Thermal Resistance from Junction to Case | 0.88 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

## Typical Performance



Figure 1. Forward Characteristics


Figure 2. Reverse Characteristics

## Typical Performance



Figure 3. Current Derating


Figure 5. Recovery Charge vs. Reverse Voltage


Figure 4. Power Derating


Figure 6. Capacitance vs. Reverse Voltage

## Typical Performance



Figure 7. Transient Thermal Impedance

## Diode Model



$$
\begin{gathered}
\mathrm{V}_{\mathrm{fT}}=\mathrm{V}_{\mathrm{T}}+\mathrm{If} * \mathrm{R}_{\mathrm{T}} \\
\mathrm{~V}_{\mathrm{T}}=0.98+\left(\mathrm{T}_{3} *-1.71 * 10^{-3}\right) \\
\mathrm{R}_{\mathrm{T}}=0.040+\left(\mathrm{T}_{3} * 5.32 * 10^{-4}\right)
\end{gathered}
$$

Note: $\mathbf{T}_{\mathbf{j}}=$ Diode Junction Temperature In Degrees Celsius



| Part Number | Package | Marking |
| :---: | :---: | :---: |
| C4D10120E | TO-252-2 | C4D10120 |

TO-252-2

## Package Dimensions

Package TO-252-2


| POS | Inches |  | Millimeters |  |
| :---: | :---: | :---: | :---: | :---: |
|  | Min | Max | Min | Max |
| A | . 250 | . 289 | 6.350 | 7.341 |
| B | . 197 | . 215 | 5.004 | 5.461 |
| C | . 027 | . 050 | . 686 | 1.270 |
| D* | . 270 | . 322 | 6.858 | 8.179 |
| E | . 178 | . 182 | 4.521 | 4.623 |
| F | . 025 | . 045 | . 635 | 1.143 |
| G | $44^{\circ}$ | $46^{\circ}$ | $44^{\circ}$ | $46^{\circ}$ |
| H | . 380 | . 410 | 9.652 | 10.414 |
| J | . 090 TYP |  | 2.286 TYP |  |
| K | $6^{\circ}$ | $8^{\circ}$ | $6^{\circ}$ | $8^{\circ}$ |
| L | . 086 | . 094 | 2.184 | 2.388 |
| M | . 018 | . 034 | . 457 | . 864 |
| N | . 035 | . 050 | . 889 | 1.270 |
| P | . 231 | . 246 | 5.867 | 6.248 |
| Q | 0.00 | . 005 | 0.00 | . 127 |
| R | R0.010 TYP |  | R0.254 TYP |  |
| S | . 017 | . 023 | . 432 | . 584 |
| T | . 038 | . 045 | . 965 | 1.143 |
| U | . 021 | . 029 | . 533 | . 737 |

Note:

* Tab "D" may not be present

 2002/95/EC on the restriction of the use of certain hazardous substances in electrical and electronic equipment (RoHS), as amended through April $21,2006$.

